

isc N-Channel MOSFET Transistor

AOK27S60L

• FEATURES

- Drain Current – $I_D = 27A @ T_c=25^\circ C$
- Drain Source Voltage-
: $V_{DSS} = 600V$ (Min)
- Static Drain-Source On-Resistance
: $R_{DS(on)} = 0.16 \Omega$ (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

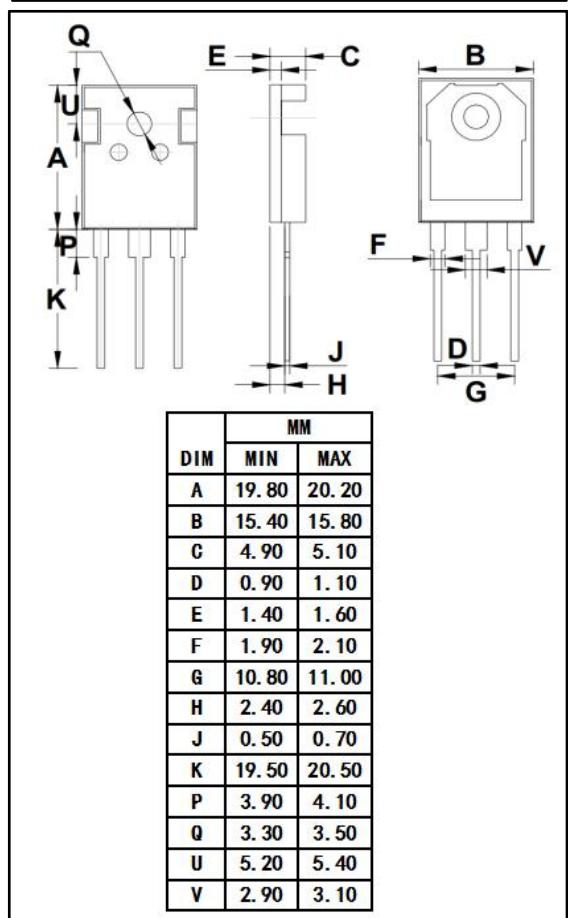
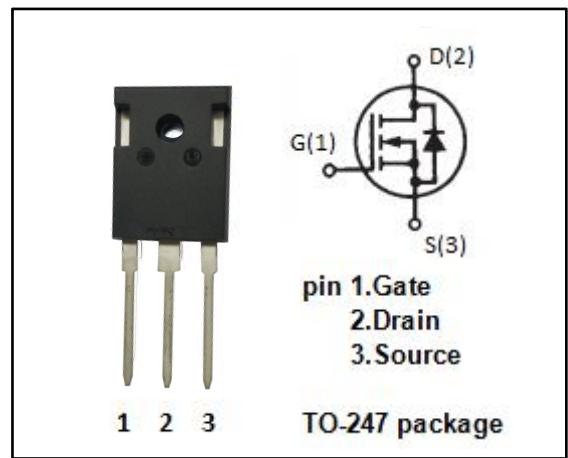
- Be suitable for synchronous rectification for server and general purpose applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	600	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-Continuous	27	A
I_{DM}	Drain Current-Single Pulsed	110	A
P_D	Total Dissipation @ $T_c=25^\circ C$	357	W
T_j	Max. Operating Junction Temperature	-55~150	°C
T_{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.35	°C/W



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ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D = 250 \mu\text{A}$	600			V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}= \text{V}_{\text{GS}}; \text{I}_D = 250 \mu\text{A}$	2.5		4	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D = 13.5\text{A}$ $\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D = 13.5\text{A}; \text{T}_J = 150^\circ\text{C}$			0.16 0.44	Ω
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}= \pm 20\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= 600\text{V}; \text{V}_{\text{GS}}= 0\text{V}$ $\text{V}_{\text{DS}}= 480\text{V}; \text{V}_{\text{GS}}= 0\text{V}$		10	1	μA
V_{SD}	Diode forward voltage	$\text{I}_{\text{S}}= 1\text{A}; \text{V}_{\text{GS}} = 0\text{V}$			1	V

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